



# 130 $\mu$ V Maximum Offset Voltage Op Amp in TSOT AD8677

## FEATURES

- Low offset voltage: 130  $\mu$ V max
- Input offset drift: 1.5  $\mu$ V/ $^{\circ}$ C max
- Low noise: 0.25  $\mu$ V p-p
- High gain, CMRR and PSRR: 115 dB min
- Low supply current: 1.1 mA
- Wide supply voltage range:  $\pm$ 4 V to  $\pm$ 18 V operation

## APPLICATIONS

- Medical and industrial instrumentation
- Sensors and controls
  - Thermocouple
  - RTDs
  - Strain bridges
  - Shunt current measurements
- Precision filters

## GENERAL DESCRIPTION

The AD8677 is the next generation of precision, ultralow offset amplifiers. It builds on the high performance of the OP07 and integrates lower power (1.1 mA typical), lower input bias current ( $\pm$ 1 nA maximum), and higher CMRR/PSRR (130 dB) in the small TSOT package. Operation is fully specified from  $\pm$ 5 V to  $\pm$ 15 V supply.

The AD8677 provides higher accuracy than industry-standard OP07-type amplifiers due to Analog Devices' iPolar™ process, which supports enhanced performance in a smaller footprint. These performance enhancements include wider output swing, lower power, and higher CMRR (common-mode rejection ratio) and PSRR (power supply rejection ratio). The AD8677 maintains stability of offsets and gain virtually regardless of variations in time or temperature. Excellent linearity and gain accuracy can be maintained at high closed-loop gains.

The AD8677 is fully specified over the extended industrial temperature range of  $-40^{\circ}$ C to  $+125^{\circ}$ C. The AD8677 amplifier is available in the tiny, 5-lead TSOT and the popular 8-lead, narrow SOIC lead-free packages.

## PIN CONFIGURATIONS

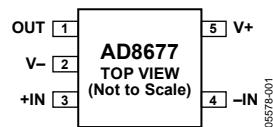


Figure 1. 5-Lead TSOT (UJ-5)

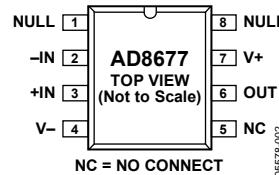


Figure 2. 8-Lead SOIC\_N (R-8)

## Rev. A

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## REVISION HISTORY

### 6/11—Rev. 0 to Rev. A

Change to Figure 43 .....	12
Updated Outline Dimensions .....	13

### 11/05—Revision 0: Initial Version

## SPECIFICATIONS

$V_S = \pm 5.0$  V,  $T_A = +25^\circ\text{C}$ , unless otherwise specified.

Table 1.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	$V_{OS}$		40	130	350	$\mu\text{V}$
Input Bias Current	$I_B$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	0.2	1	1	$\text{nA}$
Input Offset Current	$I_{OS}$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	0.1	1	1	$\text{nA}$
Input Voltage Range		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	-3.5		+3.5	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = \pm 3$ V $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	120	127		dB
Open-Loop Gain	$A_{VO}$	$R_L = 2 \text{ k}\Omega$ to ground, $V_O = \pm 3$ V $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	1000	10000		V/mV
	$\Delta V_{OS}/\Delta T$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	1000	0.5	1.4	$\mu\text{V}/^\circ\text{C}$
OUTPUT CHARACTERISTICS						
Output Voltage Swing	$V_{OUT}$	$R_L = 10 \text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	$\pm 3.95$	$\pm 4.1$		V
		$R_L = 2 \text{ k}\Omega$ to ground $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	$\pm 3.95$			V
Short-Circuit Limit	$I_{SC}$		$\pm 3.9$	$\pm 4$		V
Output Current	$I_O$	$V_O = 3.5$ V	27			mA
			15			mA
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_S = \pm 4.0$ V to $\pm 18.0$ V $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	115	130		dB
Supply Current/Amplifier	$I_{SY}$	$V_O = 0$ V $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	110	1.1	1.25	mA
					1.7	mA
DYNAMIC PERFORMANCE						
Slew Rate	SR	$R_L = 10 \text{ k}\Omega$		0.2		$\text{V}/\mu\text{s}$
Gain Bandwidth Product	GBP			0.6		MHz
Phase Margin				80		Degrees
NOISE PERFORMANCE						
Voltage Noise	$e_{n,p-p}$	0.1 Hz to 10 Hz		0.28		$\mu\text{V p-p}$
Voltage Noise Density	$e_n$	$f = 1$ kHz		10		$\text{nV}/\sqrt{\text{Hz}}$
Current Noise Density	$i_n$	$f = 1$ kHz		0.074		$\text{pA}/\sqrt{\text{Hz}}$

# AD8677

$V_S = \pm 15$  V,  $T_A = +25^\circ\text{C}$ , unless otherwise specified.

**Table 2.**

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	$V_{OS}$		45	130		$\mu\text{V}$
		$-40^\circ\text{C} \leq TA \leq +125^\circ\text{C}$		350		$\mu\text{V}$
Input Bias Current	$I_B$		0.2	1		nA
		$-40^\circ\text{C} \leq TA \leq +125^\circ\text{C}$		1		nA
Input Offset Current	$I_{OS}$		0.2	1		nA
		$-40^\circ\text{C} \leq TA \leq +125^\circ\text{C}$		1		nA
Input Voltage Range			-13.5		+13.5	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = \pm 13.0$ V $-40^\circ\text{C} \leq TA \leq +125^\circ\text{C}$	120	140		dB
		$R_L = 2 \text{ k}\Omega$ to ground, $V_O = \pm 11$ V	120			dB
Open Loop Gain	$A_{VO}$	$-40^\circ\text{C} \leq TA \leq +125^\circ\text{C}$	1000	10000		V/mV
		$-40^\circ\text{C} \leq TA \leq +125^\circ\text{C}$	1000			V/mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$-40^\circ\text{C} \leq TA \leq +125^\circ\text{C}$		0.5	1.5	$\mu\text{V}/^\circ\text{C}$
OUTPUT CHARACTERISTICS						
Output Voltage Swing	$V_{OUT}$	$R_L = 10 \text{ k}\Omega$ to ground $-40^\circ\text{C} \leq TA \leq +125^\circ\text{C}$	$\pm 13.95$	14		V
		$R_L = 2 \text{ k}\Omega$ to ground $-40^\circ\text{C} \leq TA \leq +125^\circ\text{C}$	$\pm 13.9$			V
Short Circuit Limit	$I_{SC}$	$R_L = 10 \text{ k}\Omega$ to ground $-40^\circ\text{C} \leq TA \leq +125^\circ\text{C}$	$\pm 13.75$	13.8		V
Output Current	$I_O$	$V_O = 13.5$ V		30		mA
				15		mA
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_S = \pm 4.0$ V to $\pm 18.0$ V $-40^\circ\text{C} \leq TA \leq +125^\circ\text{C}$	115	130		dB
		$V_O = 0$ V $-40^\circ\text{C} \leq TA \leq +125^\circ\text{C}$	110			dB
Supply Current/Amplifier	$I_{SY}$			1.1	1.3	mA
					1.8	mA
DYNAMIC PERFORMANCE						
Slew Rate	SR	$R_L = 10 \text{ k}\Omega$		0.2		$\text{V}/\mu\text{s}$
Gain Bandwidth Product	GBP			0.6		MHz
Phase Margin				80		Degrees
NOISE PERFORMANCE						
Voltage Noise	$e_{n,p-p}$	$0.1 \text{ Hz to } 10 \text{ Hz}$		0.25		$\mu\text{V p-p}$
Voltage Noise Density	$e_n$	$f = 1 \text{ kHz}$		10		$\text{nV}/\sqrt{\text{Hz}}$
Current Noise Density	$i_n$	$f = 1 \text{ kHz}$		0.074		$\text{pA}/\sqrt{\text{Hz}}$

## ABSOLUTE MAXIMUM RATINGS

**Table 3.**

Parameter	Value
Supply Voltage	$\pm 18\text{ V}$
Input Voltage	$\pm \text{V Supply}$
Differential Input Voltage	$\pm 0.7\text{ V}$
Output Short-Circuit Duration to GND	Indefinite
Storage Temperature Range UJ-5, R Package	$-65^\circ\text{C}$ to $+150^\circ\text{C}$
Operating Temperature Range	$-40^\circ\text{C}$ to $+125^\circ\text{C}$
Junction Temperature Range RM, R Package	$-65^\circ\text{C}$ to $+150^\circ\text{C}$
Lead Temperature (Soldering, 10 sec)	$+300^\circ\text{C}$

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## THERMAL RESISTANCE

$\theta_{JA}$  is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

**Table 4.**

Package Type	$\theta_{JA}$	$\theta_{JC}$	Unit
5-Lead TSOT (UJ-5)	207	61	$^\circ\text{C}/\text{W}$
8-Lead SOIC (R-8)	158	43	$^\circ\text{C}/\text{W}$

## ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



## TYPICAL PERFORMANCE CHARACTERISTICS

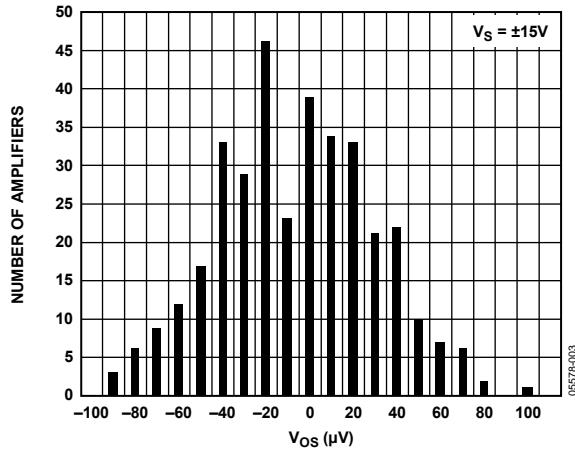


Figure 3. Input Offset Voltage Distribution

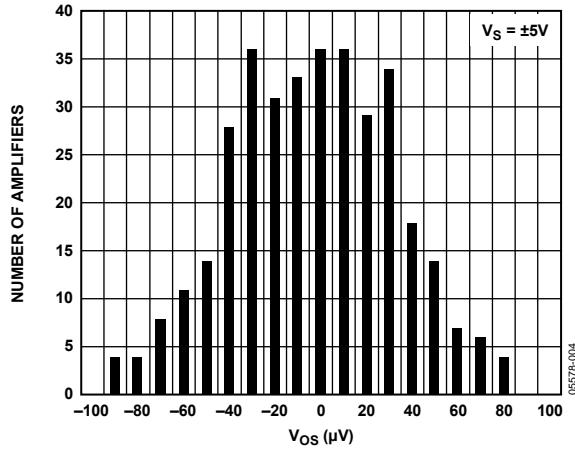


Figure 4. Input Offset Voltage Distribution

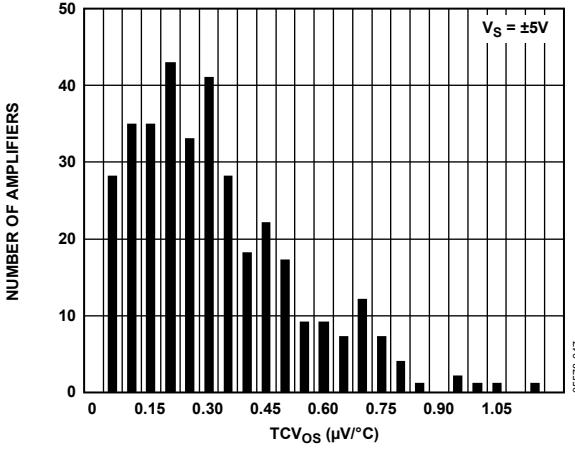
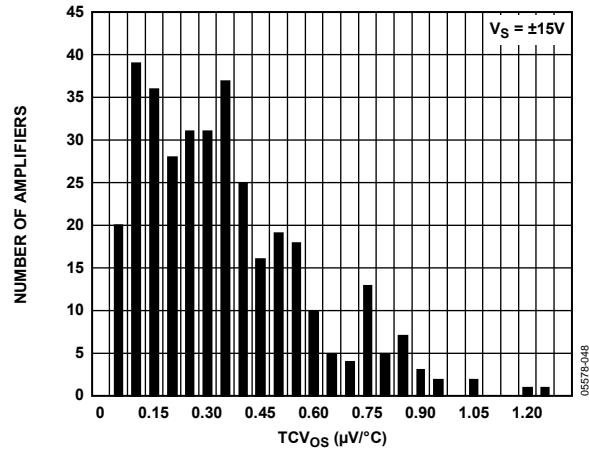
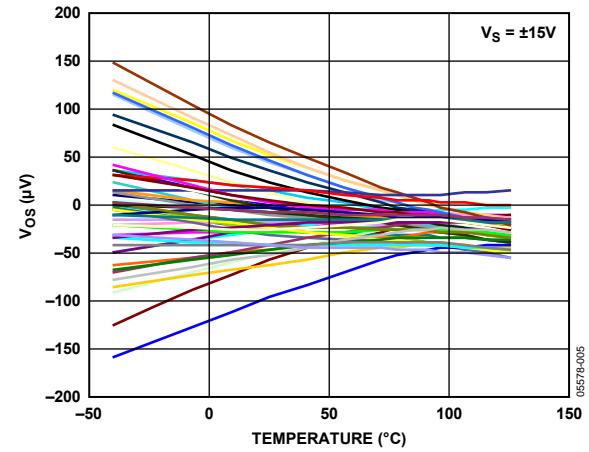
Figure 5.  $TCV_{OS}$  vs. Number of AmplifiersFigure 6.  $TCV_{OS}$  vs. Number of Amplifiers

Figure 7. Offset Voltage vs. Temperature

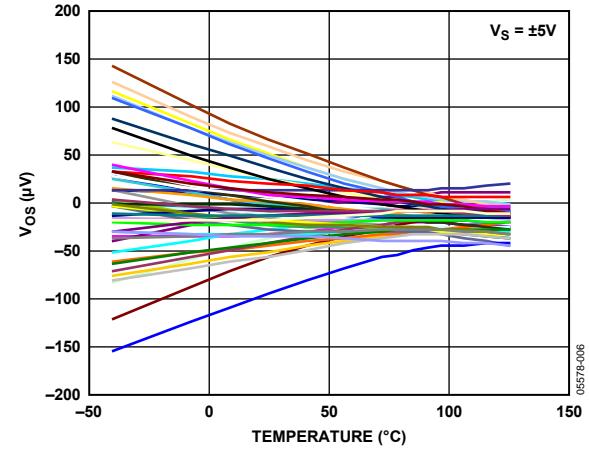
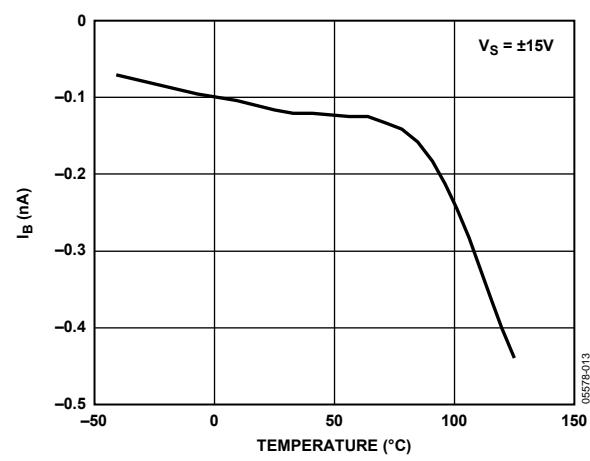
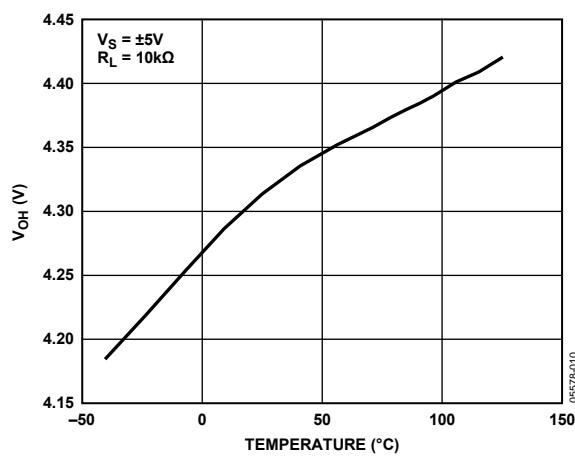
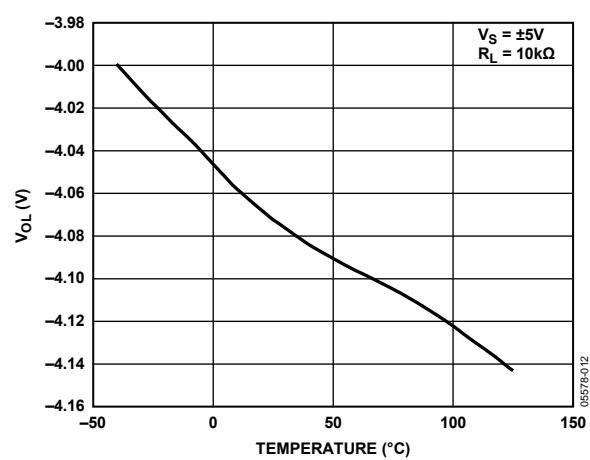
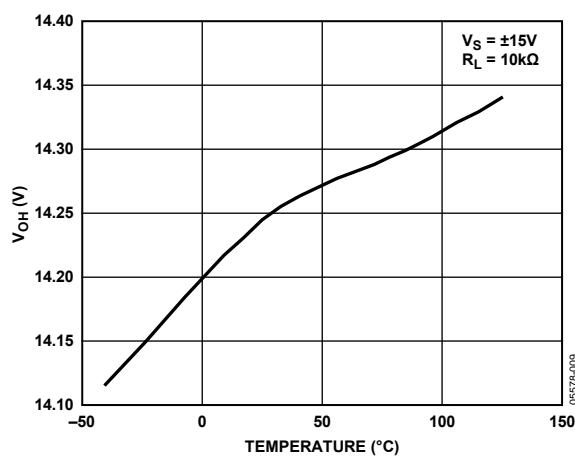
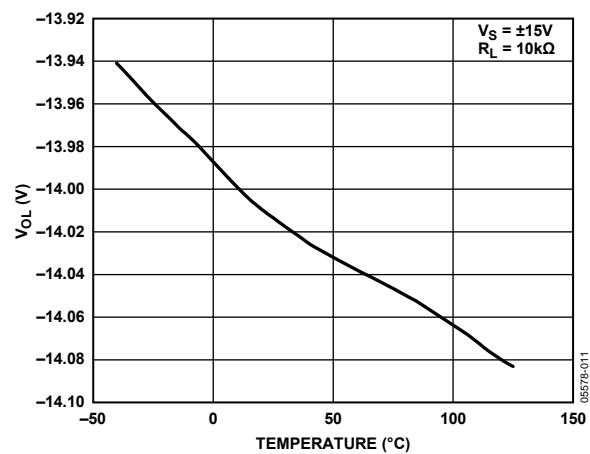
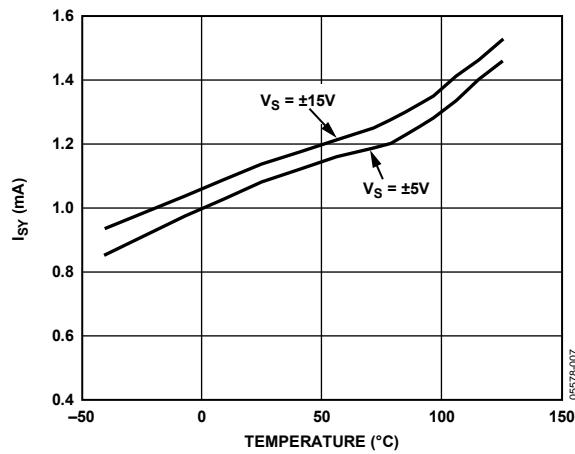
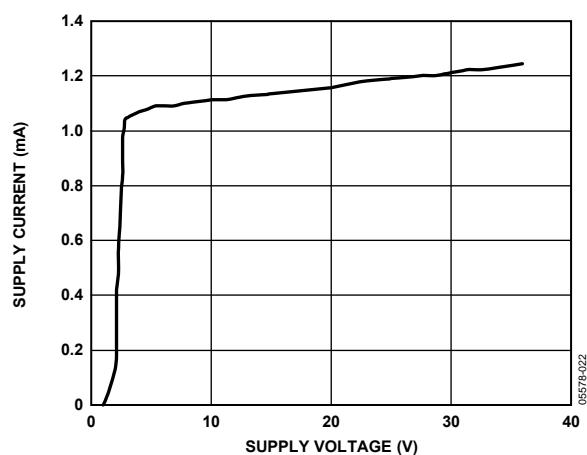
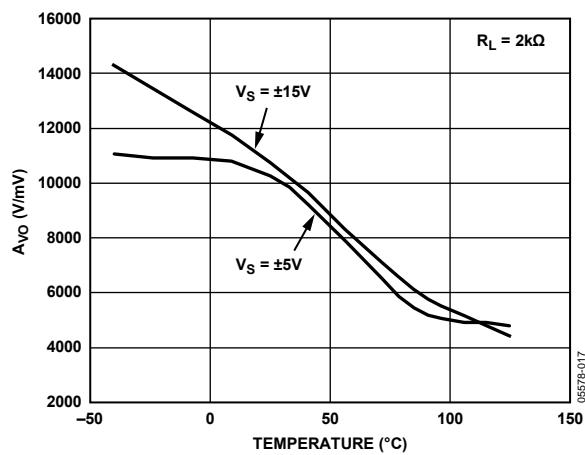
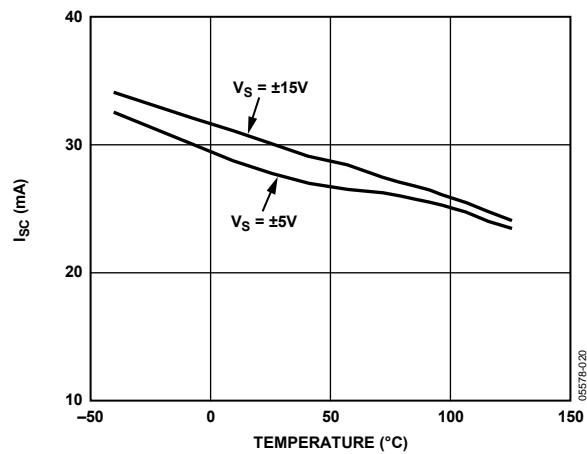
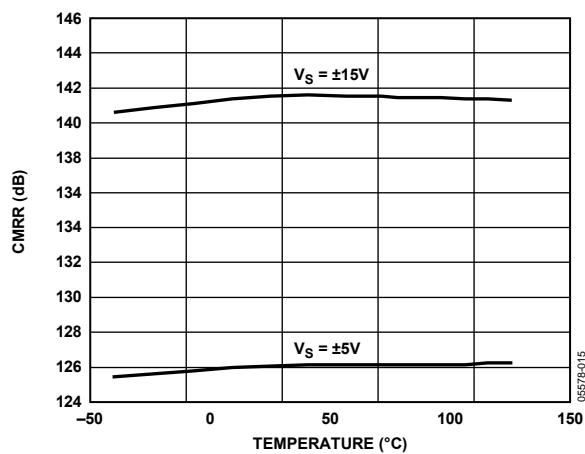
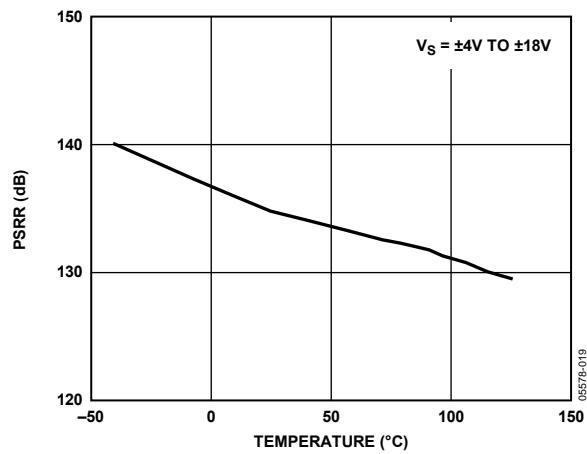
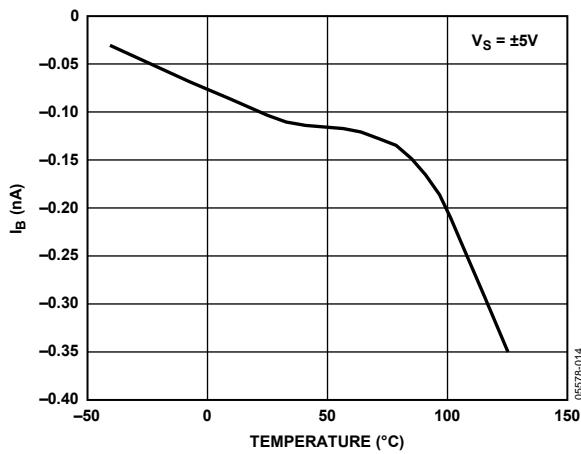
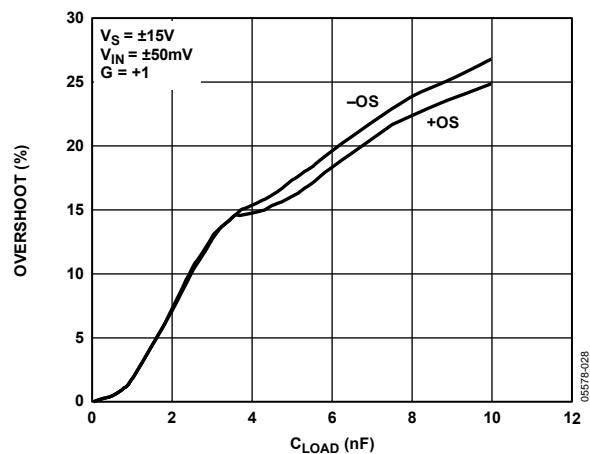
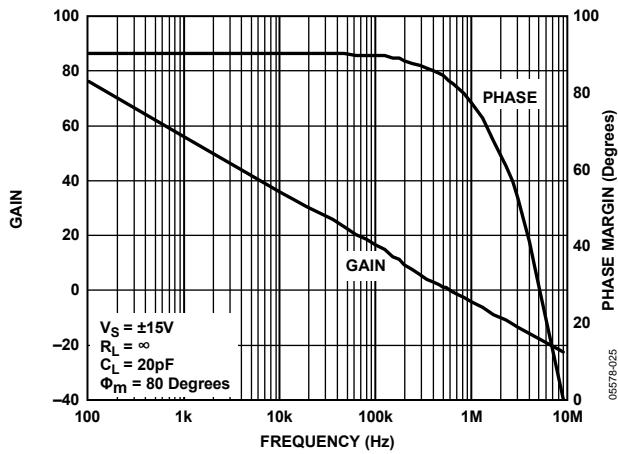
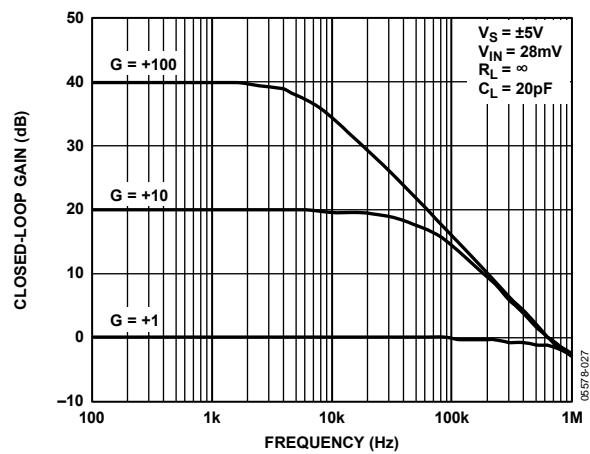
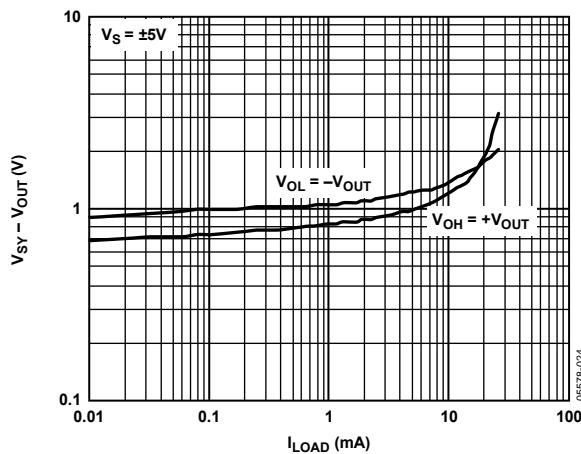
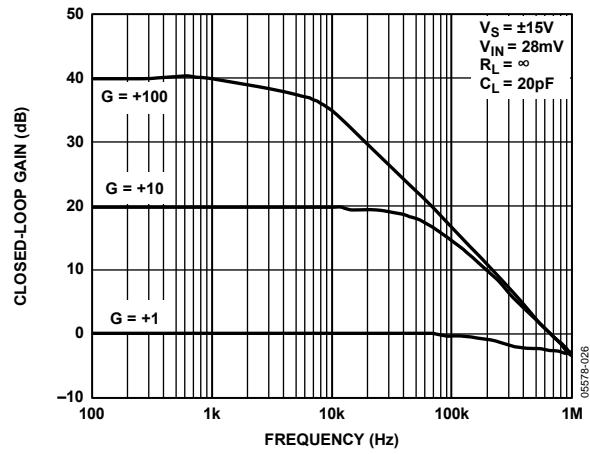
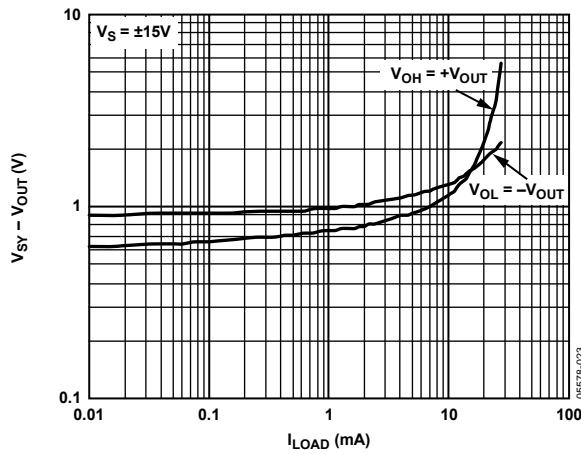


Figure 8. Offset Voltage vs. Temperature







# AD8677

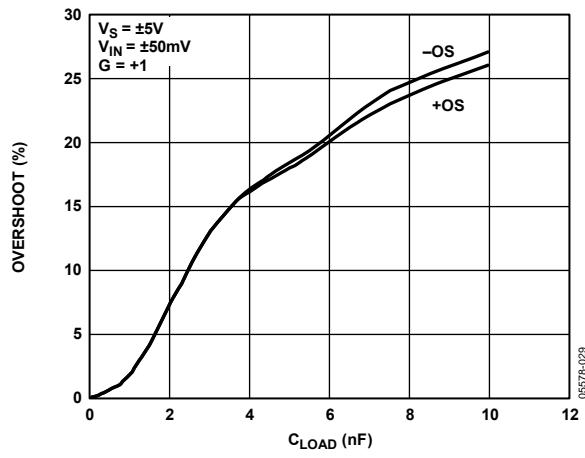


Figure 27. Overshoot vs. Capacitive Load

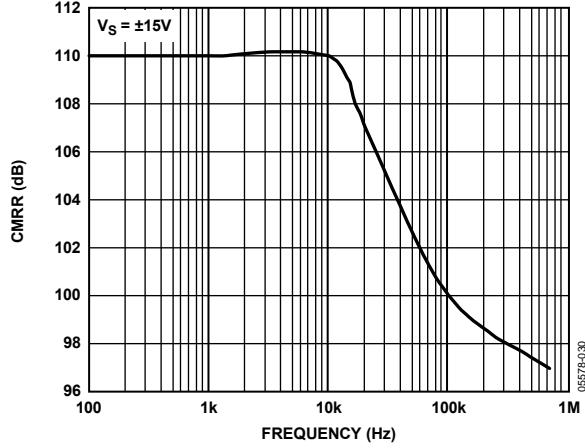


Figure 28. CMRR vs. Frequency

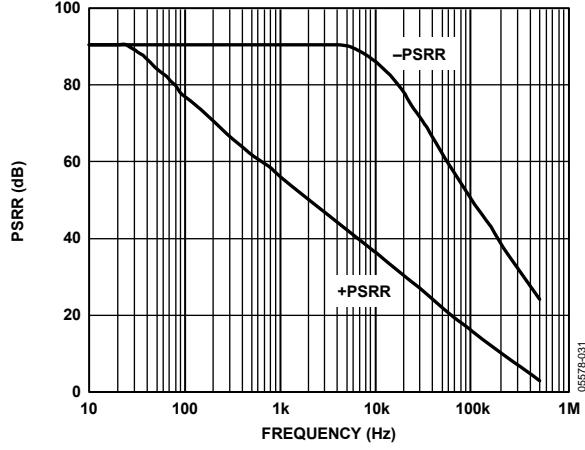


Figure 29. PSRR vs. Frequency

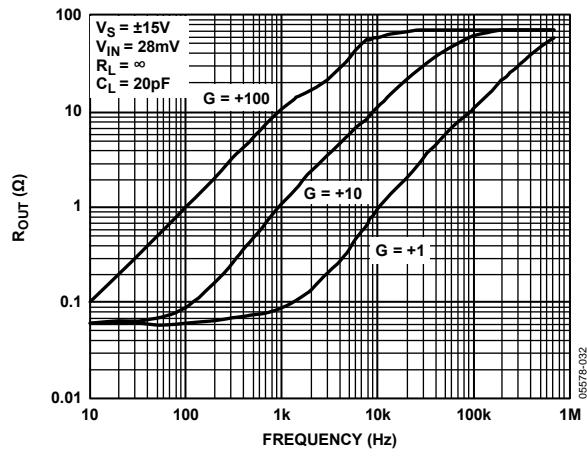


Figure 30. Output Impedance vs. Frequency

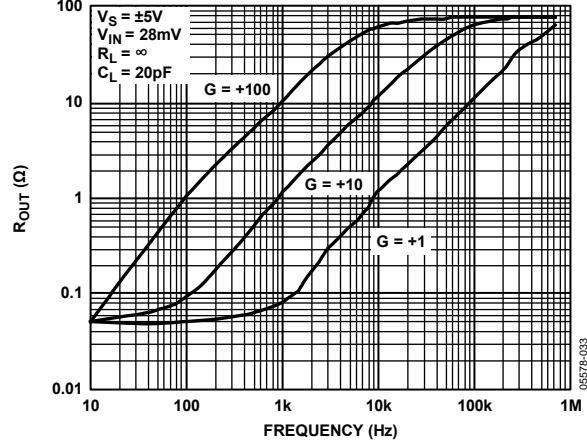


Figure 31. Output Impedance vs. Frequency

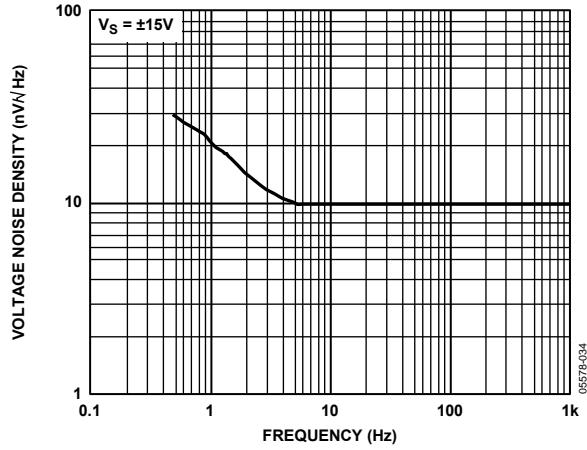


Figure 32. Voltage Noise Density vs. Frequency

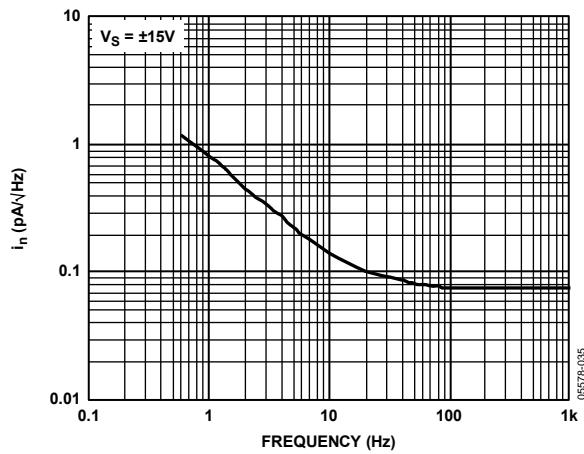


Figure 33. Current Noise Density vs. Frequency

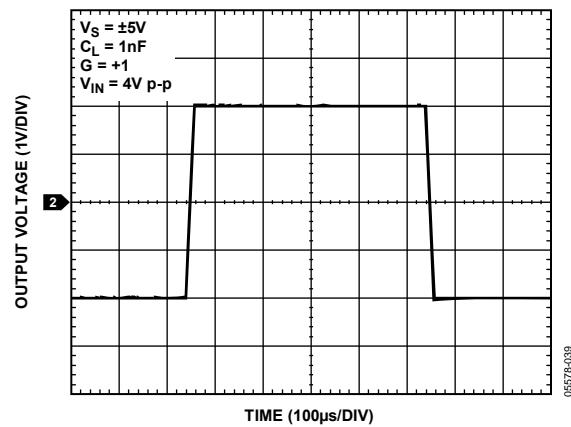


Figure 36. Large Signal Transient

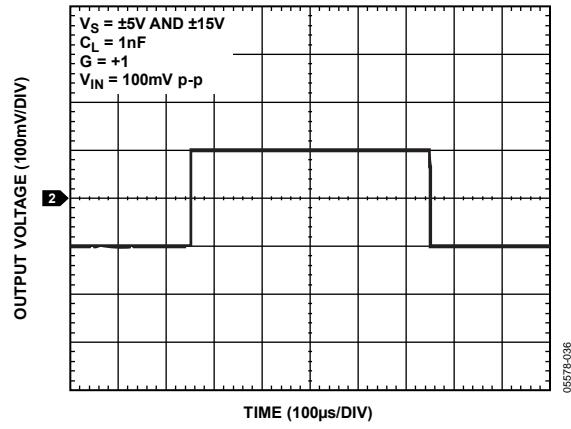


Figure 34. Small Signal Transient

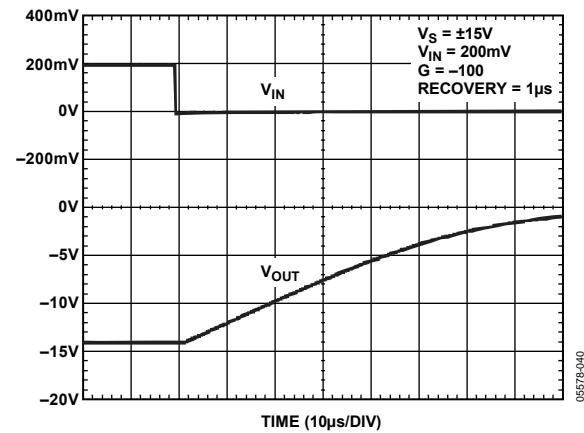


Figure 37. Positive Overload Recovery

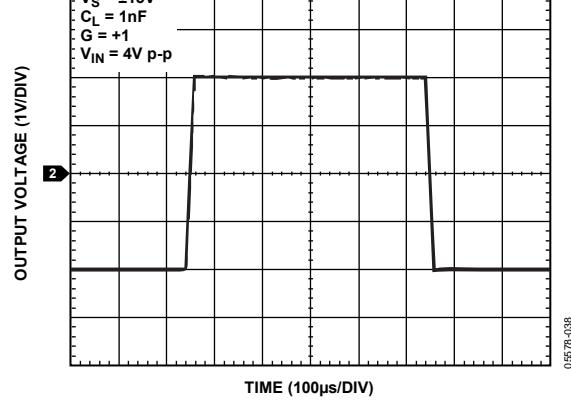


Figure 35. Large Signal Transient

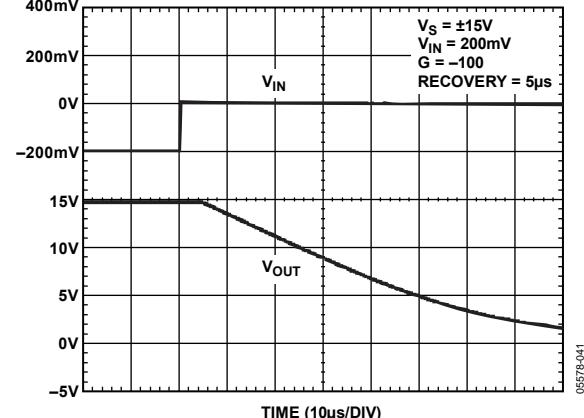


Figure 38. Negative Overload Recovery

# AD8677

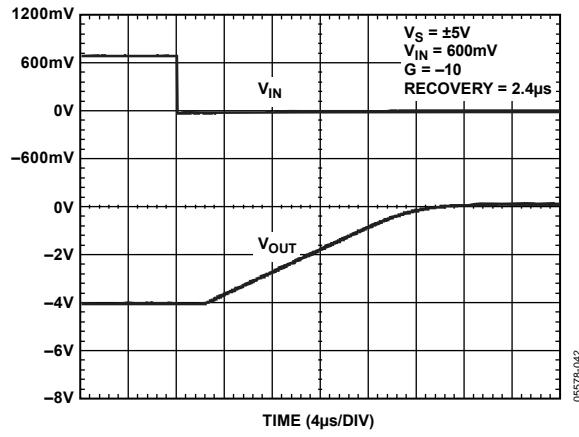


Figure 39. Positive Overload Recovery

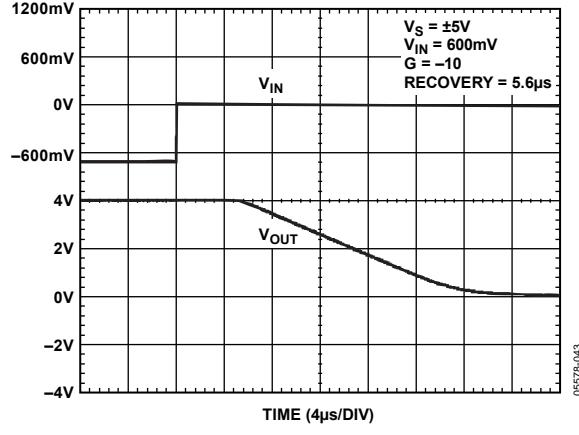


Figure 40. Negative Overload Recovery

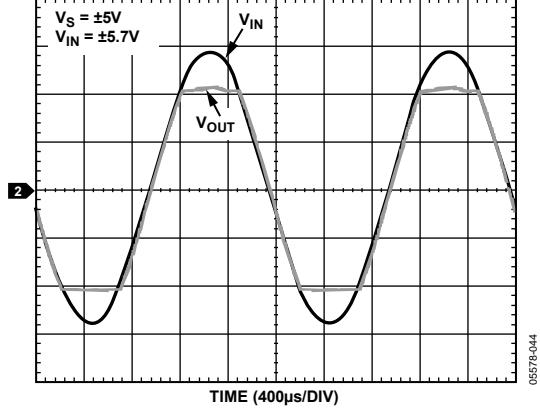


Figure 41. No Phase Reversal

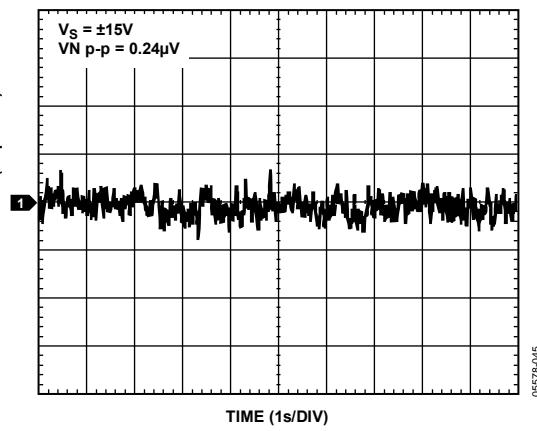


Figure 42. Voltage Noise (0.1 Hz to 10 Hz)

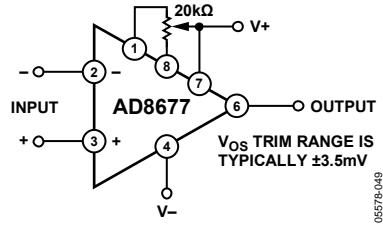


Figure 43. Optional Offset Nulling Circuit

## OUTLINE DIMENSIONS

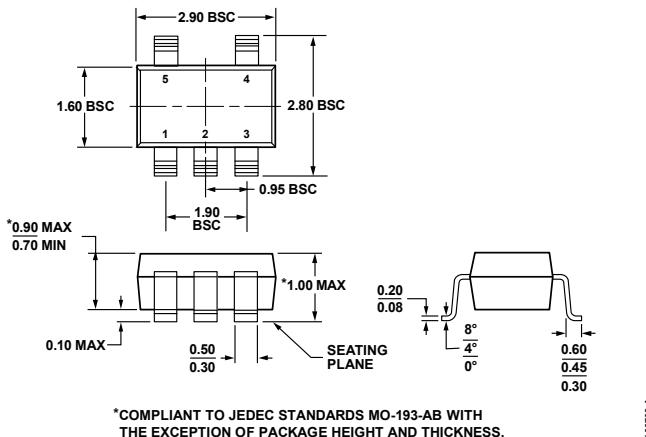


Figure 44. 5-Lead Thin Small Outline Transistor Package [TSOT]  
(UJ-5)

Dimensions shown in millimeters

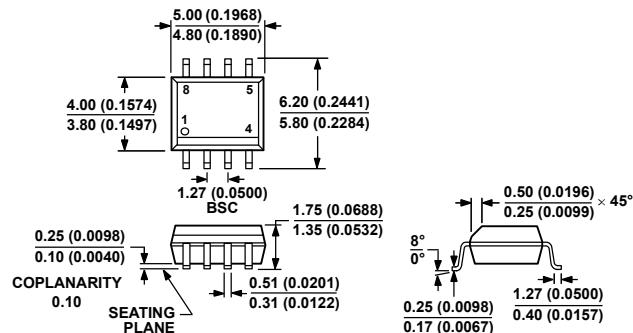


Figure 45. 8-Lead Standard Small Outline Package [SOIC\_N]  
Narrow Body  
(R-8)

Dimensions shown in millimeters and (inches)

## ORDERING GUIDE

Model <sup>1</sup>	Temperature Range	Package Description	Package Option	Branding
AD8677ARZ	-40°C to +125°C	8-Lead Standard Small Outline Package [SOIC_N]	R-8	
AD8677ARZ-REEL	-40°C to +125°C	8-Lead Standard Small Outline Package [SOIC_N]	R-8	
AD8677ARZ-REEL7	-40°C to +125°C	8-Lead Standard Small Outline Package [SOIC_N]	R-8	
AD8677AUJZ-R2	-40°C to +125°C	5-Lead Thin Small Outline Transistor Package [TSOT]	UJ-5	A0E
AD8677AUJZ-REEL	-40°C to +125°C	5-Lead Thin Small Outline Transistor Package [TSOT]	UJ-5	A0E
AD8677AUJZ-REEL7	-40°C to +125°C	5-Lead Thin Small Outline Transistor Package [TSOT]	UJ-5	A0E

<sup>1</sup> Z = RoHS Compliant Part.

**AD8677**

**NOTES**

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**NOTES**

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